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# TRANSISTORS, LOW POWER, PNP, BASED ON TYPES 2N2894 AND 2N2894A ESCC Detail Specification No. 5202/004

# ISSUE 1 October 2002





#### **ESCC Detail Specification**

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# TRANSISTORS, LOW POWER, PNP, BASED ON TYPES 2N2894 AND 2N2894A ESA/SCC Detail Specification No. 5202/004



# space components coordination group

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#### **DOCUMENTATION CHANGE NOTICE**

This Issue supersedes Issue 2 and incorporates all modification Revisions 'A' and 'B' to Issue 2 and the changes agreed in DCR's:- Cover page DCN Para. 1.2	None None None 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359 221359
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, "1" added to Characteristics ar	
, New Maximum Rating added , Unit amended to "W"	221359 221359
, One reference amended to "2"	<b>E</b>
: No. 6, Symbol amended to "T <sub>op</sub> " and to Remarks	
: No. 8, Variant references added to Ch	aracteristics 221359
, "+245" added to Maximum Ra	
, Existing Remarks deleted references added	d and Note 221359
: NOTES, Note 1 renumbered as "2"	221359
: , New Notes 1, 3 and 4 added	
Figure 2 : Existing Figure Titled as Figure 2(a) : Imperial Dimensions deleted from Tab	221359 le and Notes 221359
Figure 2(b) : New Figure added	221359
Figure 3 : Note amended	221359
Para. 4.3.2 : Text amended	221359
Para. 4.3.3 : Second sentence amended	221359
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Para. 4.4.1 : Existing text deleted and new text add Para. 4.4.2 : Existing text amended and new text add	
Para. 4.5.1 Existing text deleted and new text add	
Para. 4.5.5 : Deleted in toto	221359
Para. 4.7.2 : New paragraph added	221359
: Existing paragraph renumbered to second sentence amended	
Para. 4.7.3 : Renumbered as "4.7.5" and text ame	
Para. 4.7.4 : Title and text amended	221359
Table 2 d.c. : Nos. 5 to 12, in Test Condition amended to "01-03-05-06"	
Table 2 a.c. : Nos. 13, 14, 16, 17, in Test Condition amended to "01-03-05-06"	
Table 5 : Main heading deleted and Tables sequence	reversed in 221359
: New Titles added	221359



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#### **DOCUMENTATION CHANGE NOTICE**

Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.
		Table 5(b)  Figure 5 Para. 4.8.1 Para. 4.8.2 Paras 4.8.3 and 4.8.4 Table 6	<ul> <li>: No. 3, "1" added to Characteristics and Symbol , "Note 1" added to Conditions</li> <li>: Note 1 added</li> <li>: Main heading deleted and existing Titles amended</li> <li>: Second sentence expanded</li> <li>: Second sentence added</li> <li>: In the text, "5" amended to "5(b)"</li> <li>: Nos. 6 and 10, in Test Condition, "01-03-05" amended to "01-03-05-06"</li> </ul>	221359 221359 221359 221359 221359 221359 221359 221359
'A'	Apr. '97	P1. Cover page P2A. DCN P4. T of C P21. Appendix 'A'	<ul> <li>: Page count incremented by 1</li> <li>: Under Appendices, "None" deleted and Appendix 'A' added</li> <li>: Appendix added as new page</li> </ul>	221367 None 221367 221367
,B,	Jun. '99	P1. Cover page P2A. DCN P6. Table 1(a) Table 1(b) P9. Figure 2(b) P10. Para. 4.3.2 P11. Para. 4.4.1 Para. 4.4.2 P13. Table 2d.c. P14. Table 2d.c. Table 2a.c. P20. Table 6	<ul> <li>New Variant 07 added in the Table</li> <li>Nos. 5 and 8, In Characteristics, "Variant 06" amended to read "Variants 06 and 07"</li> <li>Subtitle amended to read "Variants 06 and 07"</li> <li>Text amended</li> <li>Second sentence amended to include Variant 07</li> <li>Second sentence amended to include Variant 07</li> <li>Nos. 5 to 10, In Conditions, "-07" added to variant entry commencing "01"</li> <li>Nos. 11 to 12, in Conditions, "-07" added to variant entry commencing "01"</li> <li>Nos. 13, 14, 16 and 17, In Conditions, "-07" added to variant entry commencing "01"</li> <li>Nos. 6 and 10, In Conditions, "-07" added to variant entry commencing "01"</li> </ul>	221517 221517



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#### 1. GENERAL

#### 1.1 SCOPE

This specification details the ratings, physical and electrical characteristics, test and inspection data for a Transistor, Low Power, PNP, based on Types 2N2894 and 2N2894A. It shall be read in conjunction with ESA/SCC Generic Specification No. 5000, the requirements of which are supplemented herein.

#### 1.2 <u>COMPONENT TYPE VARIANTS</u>

Variants of the basic transistors specified herein, which are also covered by this specification, are given in Table 1(a).

#### 1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the transistors specified herein, are scheduled in Table 1(b).

#### 1.4 PARAMETER DERATING INFORMATION

The derating information applicable to the transistors specified herein is shown in Figure 1.

#### 1.5 PHYSICAL DIMENSIONS

The physical dimensions of the transistors specified herein are shown in Figure 2.

#### 1.6 FUNCTIONAL DIAGRAM

The functional diagram, showing lead identification, of the transistors specified herein, is shown in Figure 3.

#### 1.7 HIGH TEMPERATURE TEST PRECAUTIONS

For tin-lead plated or solder-dipped lead finish, all tests to be performed at a temperature that exceeds + 125°C shall be carried out in 100% inert atmosphere.

#### 2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5000 for Discrete Semiconductors.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.

#### 3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply.



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#### **TABLE 1(a) - TYPE VARIANTS**

VARIANT	BASED ON TYPE	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	2N2894	TO18	2(a)	D2
02	2N2894A	TO18	2(a)	D2
03	2N2894	TO18	2(a)	D3 or D4
04	2N2894A	TO18	2(a)	D3 or D4
05	2N2894	TO18	2(a)	D7
06	2N2894	CHIP CARRIER	2(b)	2
07	2N2894	CHIP CARRIER	2(b)	4

#### **TABLE 1(b) - MAXIMUM RATINGS**

No.	CHARACTERISTICS	SYMBOL	MAXIMUM RATING	UNIT	REMARKS
1	Collector-Base Voltage	V <sub>CBO</sub>	- 12	V	
2	Collector-Emitter Voltage	V <sub>CEO</sub>	- 12	٧	
3	Emitter-Base Voltage	V <sub>EBO</sub>	<b>-4.5</b>	V	
4	Collector Current (Continuous)	lc	-0.2	Α	
5	Power Dissipation 1 All Variants Variants 06 and 07	P <sub>tot1</sub>	0.36 0.58 (1)	W	At T <sub>amb</sub> ≤ +25°C Note 2
6	Operating Temperature Range	T <sub>op</sub>	-55 to +175	°C	T <sub>amb</sub>
7	Storage Temperature Range	T <sub>stg</sub>	−55 to +175	°C	
8	Soldering Temperature Variants 01 to 05 Variants 06 and 07	T <sub>sol</sub>	+ 260 + 245	°C	Note 3 Note 4

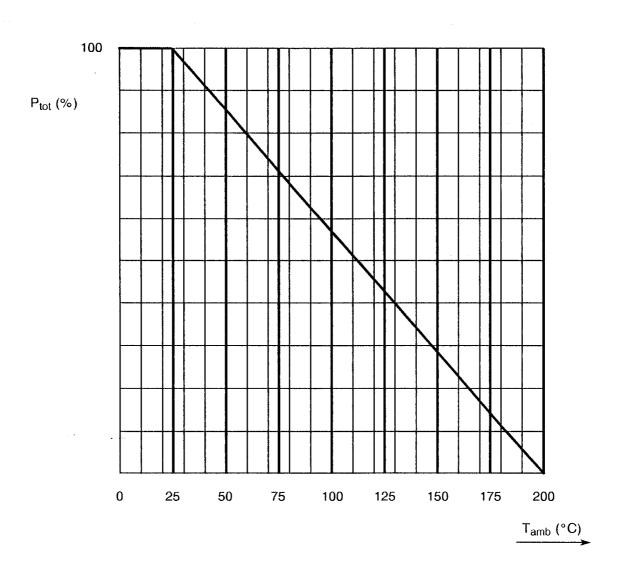
- 1. When mounted on a 15×15×0.6mm ceramic substrate.
- 2. For derating at  $T_{amb}$ > +25°C, see Figure 1.
- 3. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 4. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.



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#### FIGURE 1 - PARAMETER DERATING INFORMATION



Power Dissipation versus Temperature

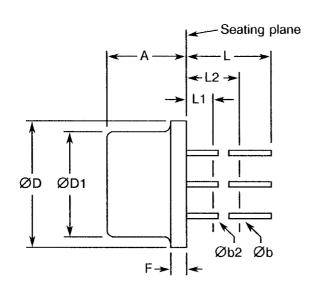


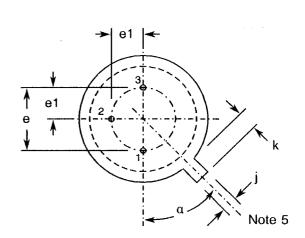
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#### **FIGURE 2 - PHYSICAL DIMENSIONS**

#### FIGURE 2(a) - VARIANTS 01 TO 05





SYMBOL	MILLIMETRES		NOTES
STWIDOL	MIN. MAX		NOTES
Α	4.32	5.33	
Øb	0.406	0.533	1
Øb2	0.406	0.483	1
ØD	5.31	5.84	
ØD1	4.52	4.95	
е	2.54 TYP.		2, 4
e1	1.27	TYP.	2, 4
F	-	0.762	
j	0.914	1.17	4
k	0.711	1.22	3
L	12.70	-	1
L1	-	1.27	1
L2	6.35	-	1
α	45°	TYP.	5

- 1. (Three leads) Øb2 applies between L1 and L2. Øb applies between L2 and 12.70mm from the seating plane. Diameter is uncontrolled in L1 and beyond 12.70mm from the seating plane.
- 2. Leads having maximum diameter 0.483mm measured in the gauging plane 1.37mm + 0.025mm 0.00mm below the seating plane of the device shall be within 0.178mm of their true position relative to a maximum-width-tab.
- 3. Measured from maximum diameter of the actual device.
- 4. The device may be measured by direct methods or by the gauge and gauging procedure described on gauge drawing GS-2.
- 5. Tab centreline.



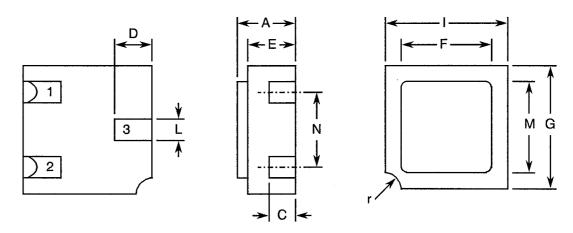
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#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

#### FIGURE 2(b) - VARIANTS 06 AND 07

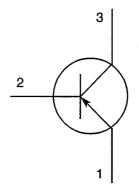


SYMBOL	MILLIMETRES		NOTES	
STIVIBUL	MIN.	MAX	NOTES	
Α	1.15	1.50		
С	0.45	0.56	1	
D	0.60	0.91	1	
E	0.91	1.12		
F	1.90	2.15		
G	2.90	3.25		
l	2.40	2.85		
L	0.40	0.60	1	
М	2.40	2.65		
N	1.80	2.00		
r	0.3	ΓΥΡ.		

#### **NOTES**

1. The three pads have the same dimensions.

#### **FIGURE 3 - FUNCTIONAL DIAGRAM**



- 1. Emitter.
- 2. Base.
- 3. Collector.

#### **NOTES**

1. For Variants 01 to 05, the collector is internally connected to the case.



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#### 4. REQUIREMENTS

#### 4.1 GENERAL

The complete requirements for procurement of the transistors specified herein shall be as stated in this specification and ESA/SCC Generic Specification No. 5000 for Discrete Semiconductors. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

#### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

#### 4.2.1 <u>Deviations from Special In-process Controls</u>

None.

#### 4.2.2 Deviations from Final Production Tests (Chart II)

None.

#### 4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

None.

#### 4.2.4 Deviations from Qualification Tests (Chart IV)

None.

#### 4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

#### 4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

#### 4.3 <u>MECHANICAL REQUIREMENTS</u>

#### 4.3.1 Dimension Check

The dimensions of the transistors specified herein shall be checked. They shall conform to those shown in Figure 2.

#### 4.3.2 Weight

The maximum weight of the transistors specified herein shall be 0.4 grammes for Variants 01 to 05 and 0.06 grammes for Variants 06 and 07.

#### 4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. For Variants 01 to 05, the test conditions shall be as follows:-

Test Condition: 'E', Lead Fatique.



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#### 4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the transistors specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

#### 4.4.1 Case

For Variants 01 to 05, the case shall be hermetically sealed and have a metal body with hard glass seals and the lid shall be welded, brazed, preform soldered or glass frit sealed.

For Variants 06 and 07, the case shall be hermetically sealed and have a ceramic body with a kovar lid.

#### 4.4.2 Lead Material and Finish

For Variants 01 to 05, the lead material shall be Type 'D' with either Type '2', Type '3 or 4' or Type '7' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

For Variants 06 and 07, the terminal finish shall be either Type '2' or Type '4' in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

#### 4.5 MARKING

#### 4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700 and the following paragraphs. When the component is too small to accommodate all of the marking specified, as much as space permits shall be marked and the marking information, in full, shall accompany the component in its primary package.

The information to be marked and the order of precedence, shall be as follows:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

#### 4.5.2 Lead Identification

Lead identification shall be as shown in Figures 2 and 3.

#### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

	<u>520200401</u>	₽
Detail Specification Number ———		
Type Variant (see Table 1(a)) ———		
Testing Level (B or C, as applicable)		J

#### 4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.



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#### 4.6 ELECTRICAL MEASUREMENTS

#### 4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3.

#### 4.6.3 <u>Circuits for Electrical Measurements</u>

Circuits for use in performing the electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

#### 4.7 BURN-IN TESTS

#### 4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb}$  = +22 ±3 °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

#### 4.7.2 Conditions for High Temperature Reverse Bias Burn-in

The requirements for high temperature reverse bias burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for high temperature reverse bias burn-in shall be as specified in Table 5(a) of this specification.

#### 4.7.3 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for power burn-in shall be as specified in Table 5(b) of this specification.

#### 4.7.4 <u>Electrical Circuits for High Temperature Reverse Bias Burn-in</u>

Circuits for use in performing the high temperature reverse bias burn-in are shown in Figure 5(a) of this specification.

#### 4.7.5 Electrical Circuits for Power Burn-in

Circuits for use in performing the power burn-in tests are shown in Figure 5(b) of this specification.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS

	OLIA DA OTENIOTICO	0.4400	MIL-STD-750	TEST COMPITIONS	LIMITS	IITS	
No.	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST CONDITIONS	MIN.	MAX.	UNIT
1	Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	3011	I <sub>C</sub> = -10mA I <sub>B</sub> = 0mA Note 1	<del>-</del> 12	<u>.</u>	V
2	Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	3001	I <sub>C</sub> = -10μΑ I <sub>E</sub> =0mA Note 1	- 12	-	V
3	Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	3026	I <sub>E</sub> = - 100µA I <sub>C</sub> = 0mA	- 4.5		V
4	Collector-Base Cut-off Current	Ісво	3036	V <sub>CB</sub> = - 10V I <sub>E</sub> = 0mA	1	- 100	nA
5	D.C. Forward Current Transfer Ratio 1	h <sub>FE1</sub>	3076	$I_C = -10$ mA $V_{CE} = -0.3$ V Variants 01-03-05-06-07 Variants 02-04 Note 1	30 -	- -	- -
6	D.C. Forward Current Transfer Ratio 2	h <sub>FE2</sub>	3076	I <sub>C</sub> = −30mA V <sub>CE</sub> = −0.5V Variants 01-03-05-06-07 Variants 02-04 Note 1	40 40	150 120	-
7	D.C. Forward Current Transfer Ratio 3	h <sub>FE3</sub>	3076	I <sub>C</sub> = − 100mA V <sub>CE</sub> = − 1.0V Variants 01-03-05-06-07 Variants 02-04 Note 1	25 30	-	-
8	Collector-Emitter Saturation Voltage 1	V <sub>CE(SAT)1</sub>	3071	I <sub>C</sub> = - 10mA I <sub>B</sub> = - 1.0mA Variants 01-03-05-06-07 Variants 02-04 Note 1		- 0.15 -	V
9	Collector-Emitter Saturation Voltage 2	V <sub>CE(SAT)2</sub>	3071	I <sub>C</sub> = −30mA I <sub>B</sub> = −3.0mA Variants 01-03-05-06-07 Variants 02-04 Note 1	-	- 0.20 - 0.19	V
10	Collector-Emitter Saturation Voltage 3	V <sub>CE(SAT)3</sub>	3071	I <sub>C</sub> = − 100mA I <sub>B</sub> = − 10mA Variants 01-03-05-06-07 Variants 02-04 Note 1		- 0.50 - 0.45	V

NOTES: See Page 14.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750	TEST CONDITIONS	LIMITS		UNIT
NO.	CHARACTERISTICS	STIVIBUL	TEST METHOD	TEST CONDITIONS	MIN.	MAX.	ONIT
11	Base-Emitter Saturation Voltage 1	V <sub>BE(SAT)1</sub>	3066	I <sub>C</sub> = -10mA I <sub>B</sub> = -1.0mA Variants 01-03-05-06-07 Variants 02-04 Note 1		- 0.98 -	٧
12	Base-Emitter Saturation Voltage 2	V <sub>BE(SAT)2</sub>	3066	I <sub>C</sub> = -30mA I <sub>B</sub> = -3.0mA Variants 01-03-05-06-07 Variants 02-04 Note 1		- 1.20 - 1.15	V

#### **NOTES**

#### TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750	TEST CONDITIONS	LIMITS		UNIT
NO.	CHARACTERISTICS	STIVIBOL	TEST METHOD	(NOTE 1)	MIN.	MAX.	UNIT
13	High Frequency Current Gain	h <sub>fe</sub>	3306	I <sub>C</sub> = −30mA V <sub>CE</sub> = −10V f = 100MHz Variants 01-03-05-06-07 Variants 02-04	4.0 7.0	1	•
14	Output Capacitance	C <sub>obo</sub>	3236	V <sub>CB</sub> = -5.0V I <sub>E</sub> = 0mA f = 1.0MHz Variants 01-03-05-06-07 Variants 02-04	-	6.0 4.5	pF
15	Emitter Transition Capacitance	C <sub>ibo</sub>	3236	V <sub>EB</sub> = -0.5V f = 1.0MHz	-	<sub>.</sub> 6.0	pF
16	Turn-on Time	t <sub>on</sub>	Figure 4	I <sub>C</sub> = −30mA I <sub>B1</sub> = 1.5mA Variants 01-03-05-06-07 Variants 02-04	- -	60 40	ns
17	Turn-off Time	<sup>t</sup> off	Figure 4	I <sub>C</sub> = -30mA I <sub>B1</sub> = -I <sub>B2</sub> = 1.5mA Variants 01-03-05-06-07 Variants 02-04	- -	90 60	ns

<sup>1.</sup> Pulsed measurement: Pulse Length ≤300μs, Duty Cycle ≤2.0%.

<sup>1.</sup> Test performed on a sample basis, LTPD 7 or less.



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#### TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750	TEST CONDITIONS	LIMITS		UNIT
140.	OTATAO (ENISTICS	3 TIVIDOL.	TEST METHOD	TEST CONDITIONS	MIN.	MAX.	ONLI
4	Collector-Base Cut-off Current	СВО	3036 Bias Cond. D	T <sub>amb</sub> = + 150°C V <sub>CB</sub> = -10V	-	-10	μА
6	D.C. Forward Current Transfer Ratio 2	h <sub>FE2</sub>	3076	$T_{amb} = -55^{\circ}C$ $V_{CE} = -0.5V$ $I_{C} = -30mA$ Note 1	20	-	-

<sup>1.</sup> Pulse measurement: Pulse Length = 300µs, Duty Cycle ≤ 2.0%.

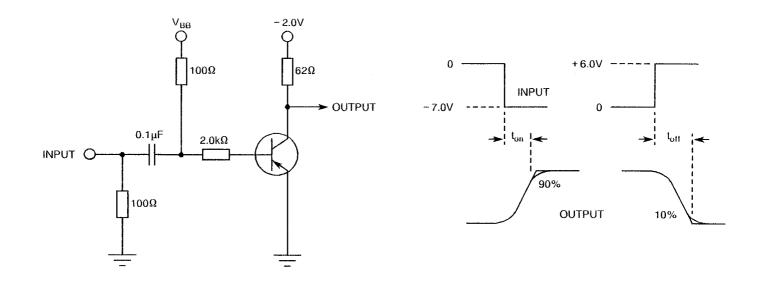


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#### FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS

#### TEST CIRCUIT FOR MEASUREMENT OF SWITCHING TIMES



GENERATOR:

 $Z_{\rm out} = 50\Omega$ 

 $t_r \leq 1.0$ ns

PW > 200ns

OSCILLOSCOPE:

 $t_r \leq 1.0$ ns

 $Z_{in} \ge 100k\Omega$   $C_{in} \le 12pF$ 

1. 
$$t_{off}$$
  $V_{BB} = +3.0V$   
 $t_{off}$   $V_{BB} = -4.0V$ 



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#### **TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMIT (Δ)	UNIT
4	Collector-Base Cut-off Current	Ісво	As per Table 2	As per Table 2	±20 or (1) ±100	nA %
6	D.C. Forward Current Transfer Ratio 2	h <sub>FE2</sub>	As per Table 2	As per Table 2	± 15	%
10	Collector-Emitter Saturation Voltage 3	V <sub>CE(SAT)3</sub>	As per Table 2	As per Table 2	±50 or (1) ±15	mV %

#### **NOTES**

1. Whichever is the greater, referred to the initial value.



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#### TABLE 5(a) - CONDITIONS FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN

No.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Case Temperature	T <sub>case</sub>	+ 150	°C
2	Collector-Base Voltage	V <sub>CB</sub>	<del>-</del> 12	V
3	Duration	t	72	hrs

#### TABLE 5(b) - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS

No.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T <sub>amb</sub>	+25	°C
2	Collector-Emitter Voltage	V <sub>CE</sub>	- 10	V
3	Power Dissipation 1	P <sub>tot1</sub>	360 (Note 1)	mW

#### **NOTES**

1. See Item 5 of Table 1(b) and Figure 1.

#### FIGURE 5(a) - ELECTRICAL CIRCUIT FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN

Not applicable.

FIGURE 5(b) - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TESTS

Not applicable.



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### 4.8 <u>ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION No. 5000)</u>

#### 4.8.1 <u>Electrical Measurements on Completion of Environmental Tests</u>

The parameters to be measured on completion of environmental tests are scheduled in Table 2. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.8.2 <u>Electrical Measurements at Intermediate Points and on Completion of Endurance Tests</u>

The parameters to be measured at intermediate points and on completion of endurance testing are scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb}$  = +22 ±3 °C.

#### 4.8.3 Conditions for Operating Life Tests (Part of Endurance Testing)

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The conditions for operating life testing shall be the same as specified in Table 5(b) for the power burn-in test.

#### 4.8.4 Electrical Circuits for Operating Life Tests

The circuit to be used for performance of the operating life test shall be the same as shown in Figure 5(b) for power burn-in.

#### 4.8.5 Conditions for High Temperature Storage Test (Part of Endurance Testing)

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 5000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.



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### TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	UNIT
4	Collector-Base Cut-off Current	I <sub>CBO</sub>	As per Table 2	As per Table 2	-	- 100	nA
6	D.C. Forward Current Transfer Ratio	h <sub>FE2</sub>	As per Table 2	As per Table 2 Variants 01-03-05-06-07 Variants 02-04	40 40	150 120	-
10	Collector-Emitter Saturation Voltage	V <sub>CE(SAT)3</sub>	As per Table 2	As per Table 2 Variants 01-03-05-06-07 Variants 02-04	<u>-</u>	- 0.50 - 0.45	V



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#### **APPENDIX 'A'**

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#### AGREED DEVIATIONS FOR SGS-THOMSON (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.2	For Chip Carrier Variants, the visual criteria called up by Para. 9.1, as specified in Paras. 3.2.5(i) and (j) of ESA/SCC Basic Specification No. 2045000, may be omitted provided that a Radiographic Inspection to verify the die-attach process is performed in accordance with Para. 9.12.
	The Radiographic Inspection shall be performed on a sample basis in accordance with STC Procedure 0011828.